

## COURSE SYLLABUS AND SCHEDULE

<u>Week</u>	<u>Lecture Dates</u>	<u>Topics</u>	<u>Chapter</u>
1	1/17, 1/19	<b>Semiconductor Fundamentals:</b> introduction, semiconductors	1
2	1/22, 1/24, 1/26	... carrier properties, distributions, and concentrations	2
3	1/29, 1/31, 2/2	... carrier action	3
4	2/5, 2/7, 2/9^	<b>Metal-Semiconductor Contacts</b>	14
5	2/12, 2/14, 2/16	<b>pn Junction Diode:</b> electrostatics	5
6	2/21, 2/23^	... <i>I-V</i> characteristics	6
7	2/26, 2/28, 3/2	... junction capacitance, transient response, applications	7, 8, 9
8	3/5, 3/7, 3/9^	<b>Bipolar Junction Transistor:</b> structure and operation	10
9	3/12, 3/14, 3/16	... BJT static characteristics	11
10	3/19, 3/21, 3/23	... BJT dynamic performance. <b>PNPN Devices.</b>	12 & 13
<i>(Spring Recess 3/26-3/30)</i>			
11	4/2, 4/4^, 4/6	<b>Metal-Oxide-Semiconductor Capacitor</b>	16 & 18
12	4/9, 4/11, 4/13	<b>MOS Field-Effect Transistor:</b> structure and operation	17
13	4/16, 4/18, 4/20^	... short-channel effects	19
14	4/23, 4/25, 4/27*	... CMOS technology and MOSFET scaling	4
15	4/30, 5/2, 5/4^	... MOS memory devices and charge-coupled devices	
16	5/7	Review	

**FINAL EXAM:** Saturday 5/12, 12:30-3:30 PM

^Quiz date

Quiz 1 topics: Semiconductor fundamentals

Quiz 2 topics: Carrier action, metal-semiconductor contacts

Quiz 3 topics: pn junction diode electrostatics, *I-V* characteristics

Quiz 4 topics: pn junction capacitance, transient response, BJT fundamentals

Quiz 5 topics: BJT static and dynamic characteristics, MOS capacitor

Quiz 6 topics: MOSFETs

\*Design Project Due